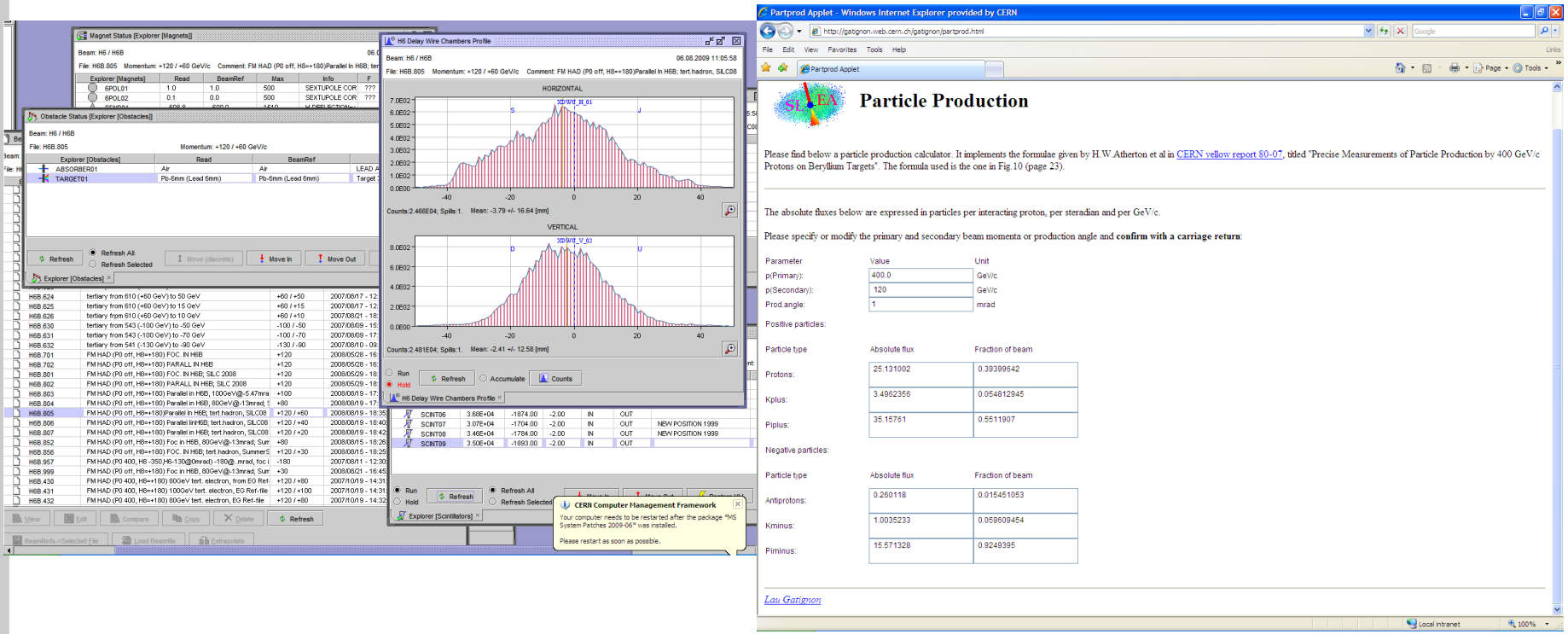
DEPFET TB summary

DEPFET Belle-II meeting – August 25th 2009

Marcel Vos, IFIC Valencia



Thanks to valuable help from SPS staff (in particular Hedda Gschwendtner and Horst Breuker) we were able to better control the beam energy and composition (electron beam, absorber)

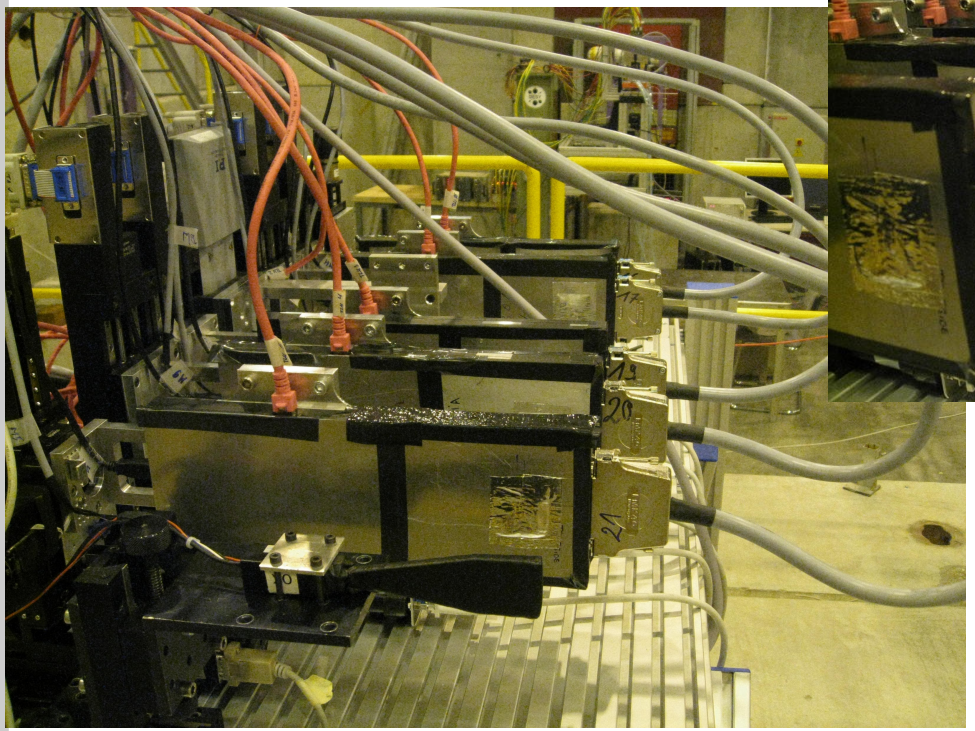
Operational experience

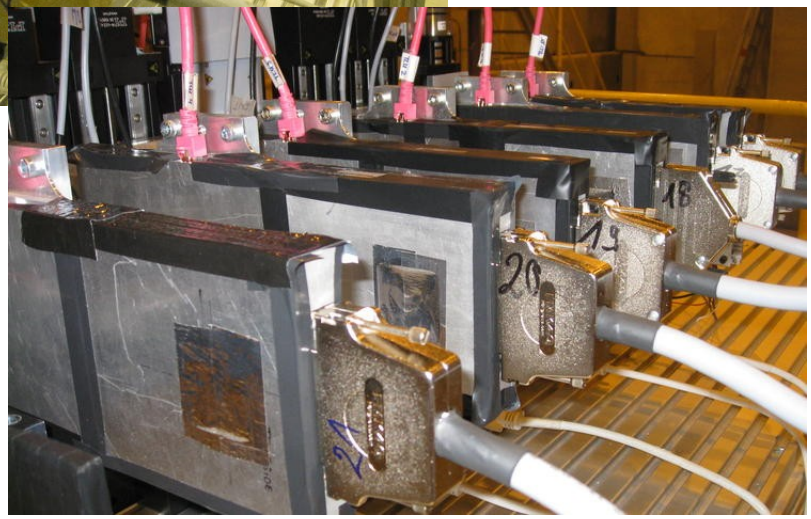
Two CCCG modules were assembled, but had to be discarded. A third module was built in Bonn during while the TB was being set up at CERN. Having no time and no means to test it, it was characterized at CERN by Christian and Carlos, initially with a CERN Cd source (that took 20 man hours to achieve) and finally in the beam.

First correlations in S3b multi-module system: discovered problem with “sliding” start gate. Solved by changing read-out sequence and reprogramming FPGAs (Sergey, Jochen)

Large common-mode noise, solved by reducing the frame time (9.6 ms → 1.2 ms)

TB2009



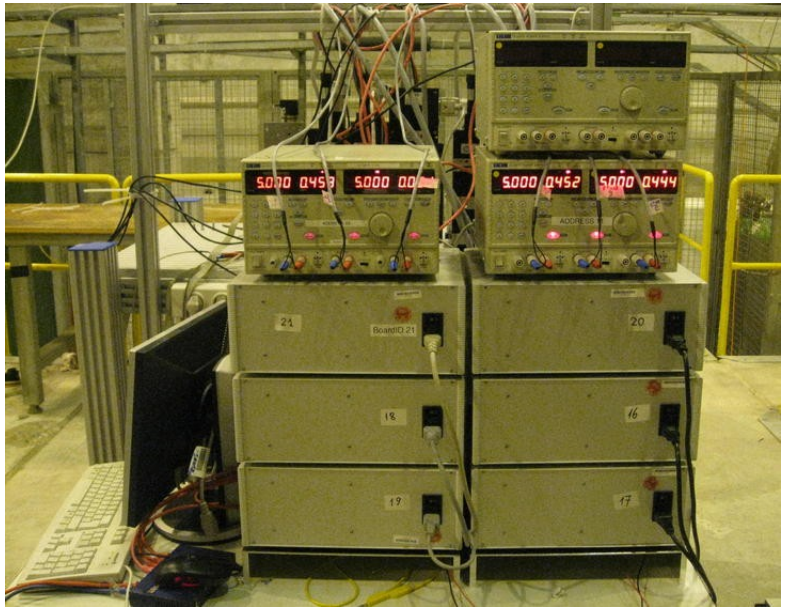


DEPFET is plug-and-play

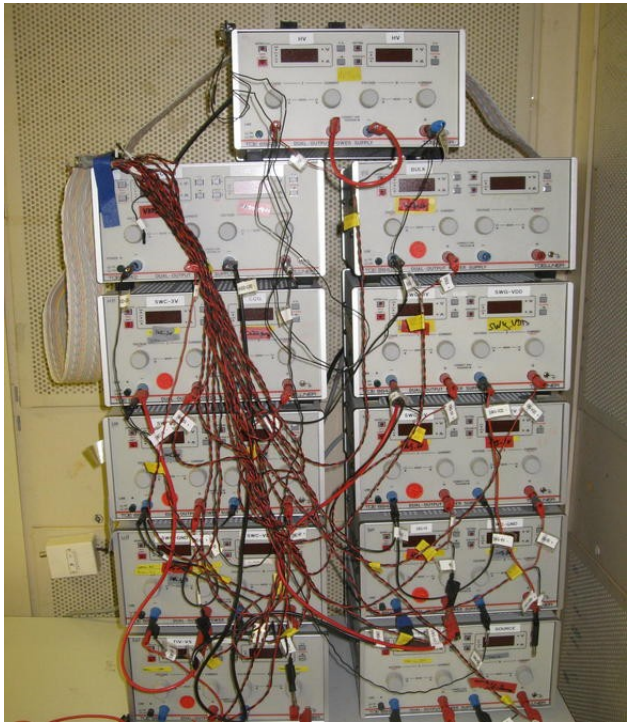
Results from characterization match results in TB

(this sounds trivial, but you may remember in 2008 things were quite different!)

The stack of power supplies for six modules is still quite impressive, but much less scary

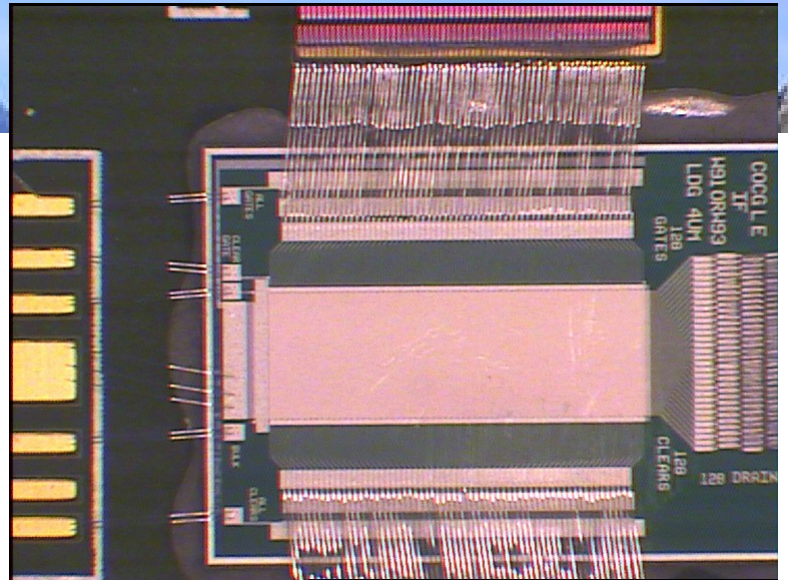


Compare this single-module stack



Excellent work by Bonn!

TB2009



New “telescope” succesfully built

- 128x128 pixel PXD5 matrices (32x24) read using the S3b system, the new work-horse
  - ➔ Bonn, tutorial
- Standard power supplies
  - ➔ Johannes and others (Bonn)
- Centralized characterization at MPI
  - ➔ Jelena + visiting experts

DUTs:

- Irradiated module could not be tested (matrix died beforehand)
- CCCG module (SB default). First two modules are behaving badly (noisy pixels, hot spots). A third module was bonded in Bonn, shipped to CERN, characterized in the beam.
- Smaller pixel size, short gate length (20x20 μm^2)
- Even shorter gate length could not be tested due to technology problem

http://aldebaran.hll.mpg.de/twiki/bin/view/DepfetInternal/Meetings
http://aldebaran.hll.mpg.de/twiki/bin/view/DepfetInternal/ShoppingMall

TB2009 modules

erational matrices on Hybrid 3.0 (S3b-System 128x128):

afer	ID	Type	Hybrid	Comment	
	J12	C3GL A	H 3.0.01	6 dead rows, working fine	
	C03	COCG L E	H 3.0.02	working, but 11 mA current at Clear_Low, 3 bond wires removed from clear switcher	
0	C02	COCG S E	H 3.0.03	working fine 29/07/09	
	G11	COCG S E	H 3.0.04	working fine, Opt. finished, SNR 17.1 (22keV), excellent DUT module	
	C14	COCG S E	H 3.0.05	working fine - not really 29/07/09	
	G08	COCG L B	H 3.0.06	working fine exept one hotspot, Opt. finished, SNR 19.1 (Cd 22keV)	
	H09	COCG V S	H 3.0.07	20x20µm², SNR 28.9 (22keV), excellent DUT module	
	G08	COCG L B	H 3.0.08	gate on voltage not stable, dead rows and dead columns	
	B02	COCG L B	H 3.0.09	2 Ch/Curo dead, enhanced current to sourceand Analog CURO	
	J10	COCG L B	H 3.0.10	Good module, SNR 17.5 (22keV), one dead column	
	M12	COCG L B	H 3.0.11	Excellent module, SNR 17.7 (22keV)	
	B02	COCG L B	H 3.0.12	Excellent module, SNR 17.8 (22keV)	
	D14	C3GL A	H 3.0.13	Many hot spots, Current in Gate, enhanced source current, bad mounting	
	M08	COCG L E	H 3.0.14	München	clear-source current, enhanced source current, bad mounting
	K11	C3GL A	H 3.0.15	München	Many noisy pixels
	G08	COCG L B	H 3.0.16	CERN	Excellent module, SNR 18.2 (22keV)
	H13	COCG L E	H 3.0.17	München	Technology related problems - not good matrix
	C11	COCG L B DG 5	H 3.0.18	CERN	Dead

A star is born

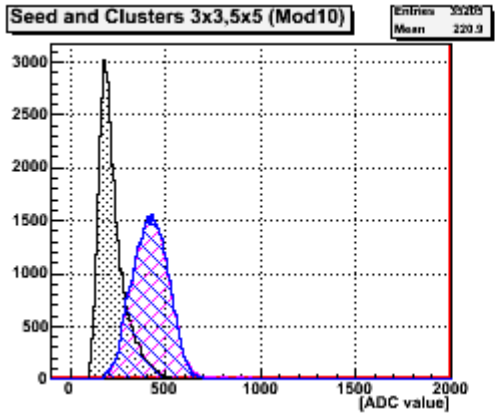
90 H09 COCG V S H 3.0.07 20x20μm², SNR 28.9 (22keV), excellent DUT module

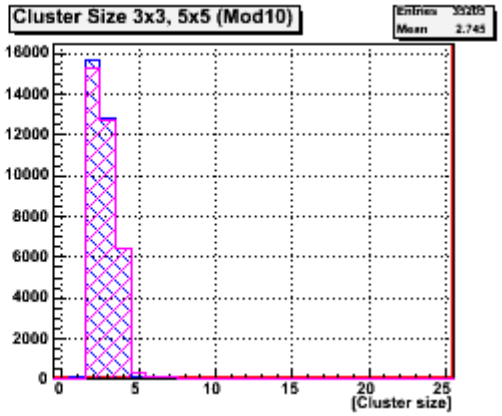
Small pixels and 5 um gate length (telescope modules = 6 um, shortest gate length = 4 um)

Over 60 % increase in signal/noise ratio with respect to telescope modules

Excellent quality (no dead/hot columns/rows/spots)

Excellent stability (no noise tails)





TB2009: programme

Voltage scans: Cross-check, we're running in optimal settings

- V_{Bias} to the wafer 110-220V

Edge scans: to study distortion of position towards the edges

- changes to position, V_{Edge}

Beam energy scan: To analyse wheter the separation "multi-scattering-intrinsic resolution" is performed correctly

80, 100, 120 GeV

electrons with 40, 60, 80 GeV

Large statistics:

- Charge collection uniformity studies
- In-pixel studies

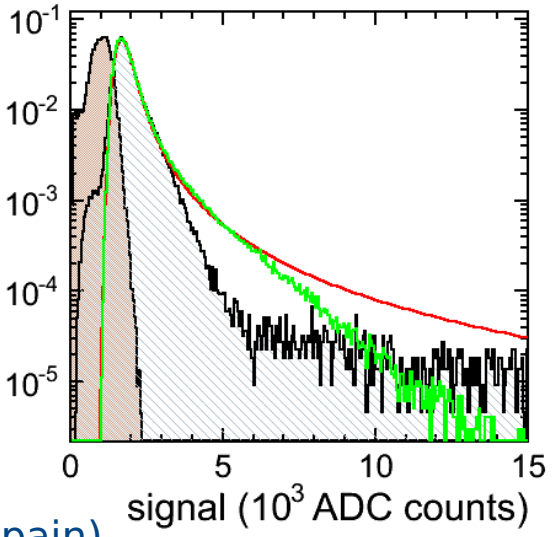
Large intensity

Two-track resolution

Outlook

Finalize write-up of TB2008

Comparison data-MC (validate digitizer, Benjamin, Zbynek, Marcel)
Energy scan



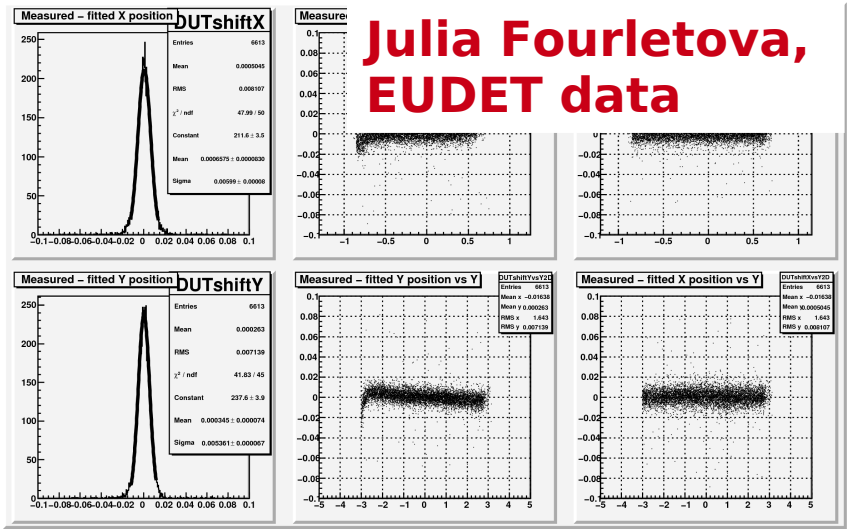
Document TB2009

Characterization (Jelena, Christian K.)
Online logbook

Prepare analysis

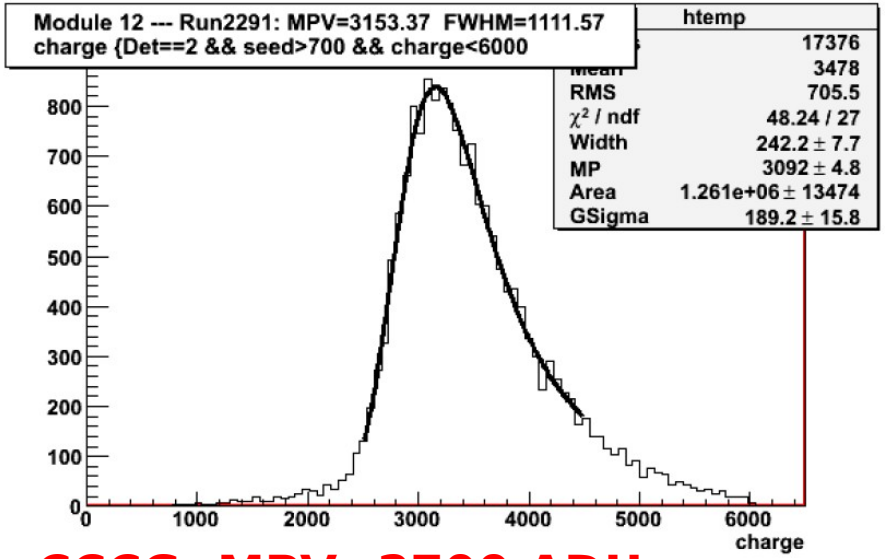
Software repository (Julia)
Data backup (IFIC, done)
Data access and shipping (investigating GRID-CSIC in Spain)
Data pre-processing (Christian G.)

Some preliminary results

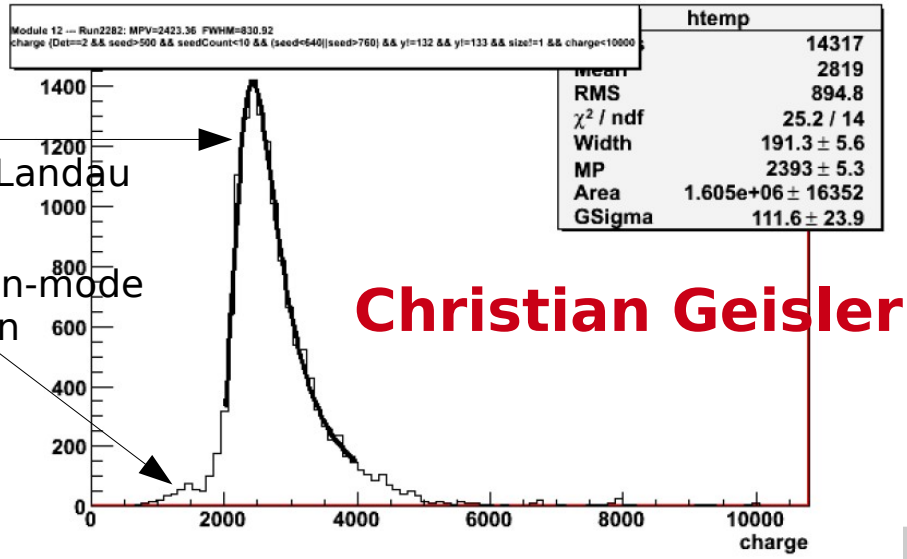


Julia Fourletova, EUDET data

20x20 mm^2 :MPV=3150 ADU



CCCG :MPV=2700 ADU



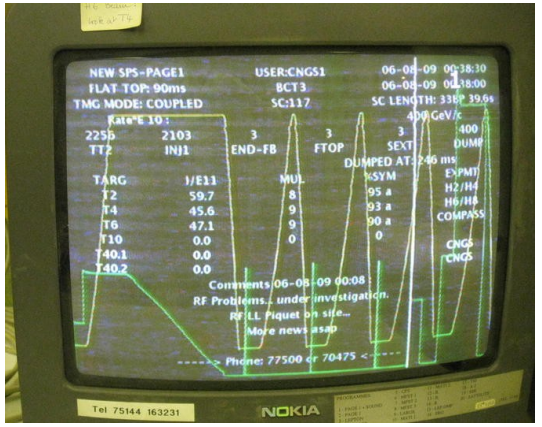
Your result could be here!

Convolution of Landau and Gaussian

Robust common-mode noise correction

Christian Geisler

Conclusions



Thanks to the whole team (+ support from the rest of the collaboration)